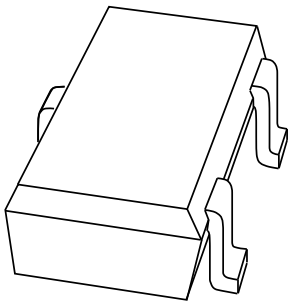


# DATA SHEET



**BFS540**

**NPN 9 GHz wideband transistor**

Product specification  
Supersedes data of 1997 Dec 05

2000 May 30



# NPN 9 GHz wideband transistor

# BFS540

## FEATURES

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability
- SOT323 package.

## APPLICATIONS

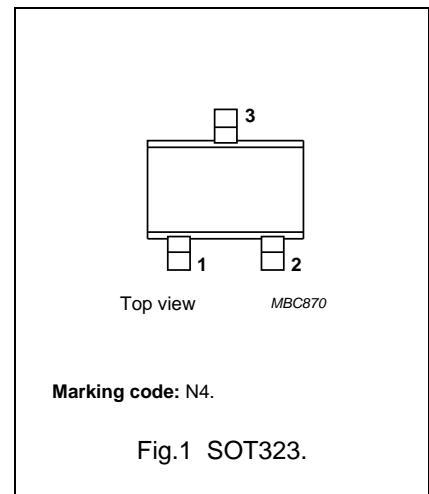
RF wideband amplifier applications such as satellite TV systems and RF portable communication equipment with signal frequencies up to 2 GHz.

## DESCRIPTION

NPN transistor in a SOT323 plastic package.

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–	20	V
$V_{CEO}$	collector-emitter voltage	open base	–	–	15	V
$I_C$	DC collector current		–	–	120	mA
$P_{tot}$	total power dissipation	$T_s \leq 80\text{ °C}$ ; note 1	–	–	500	mW
$h_{FE}$	DC current gain	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $T_j = 25\text{ °C}$	100	120	250	
$f_T$	transition frequency	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 1\text{ GHz}$ ; $T_{amb} = 25\text{ °C}$	–	9	–	GHz
$G_{UM}$	maximum unilateral power gain	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	14	–	dB
F	noise figure	$I_C = 10\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	1.3	1.7	dB

### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

## LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	20	V
$V_{CES}$	collector-emitter voltage	$R_{BE} = 0$	–	15	V
$V_{EBO}$	emitter-base voltage	open collector	–	2.5	V
$I_C$	DC collector current		–	120	mA
$P_{tot}$	total power dissipation	$T_s \leq 80\text{ °C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	150	°C
$T_j$	junction temperature		–	175	°C

### Note

1.  $T_s$  is the temperature at the soldering point of the collector tab.

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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$T_s \leq 80\text{ °C}$ ; note 1	190	K/W

## Note

- $T_s$  is the temperature at the soldering point of the collector tab.

## CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector cut-off current	$I_E = 0$ ; $V_{CE} = 8\text{ V}$	–	–	50	nA
$h_{FE}$	DC current gain	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$	100	120	250	
$C_e$	emitter capacitance	$I_C = i_c = 0$ ; $V_{EB} = 0.5\text{ V}$ ; $f = 1\text{ MHz}$	–	2	–	pF
$C_c$	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 8\text{ V}$ ; $f = 1\text{ MHz}$	–	0.9	–	pF
$C_{re}$	feedback capacitance	$I_C = 0$ ; $V_{CB} = 8\text{ V}$ ; $f = 1\text{ MHz}$	–	0.6	–	pF
$f_T$	transition frequency	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 1\text{ GHz}$ ; $T_{amb} = 25\text{ °C}$	–	9	–	GHz
$G_{UM}$	maximum unilateral power gain (note 1)	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	14	–	dB
		$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 2\text{ GHz}$ ; $T_{amb} = 25\text{ °C}$	–	8	–	dB
$ s_{21} ^2$	insertion power gain	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	12	13	–	dB
F	noise figure	$\Gamma_s = \Gamma_{opt}$ ; $I_C = 10\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	1.3	1.8	dB
		$\Gamma_s = \Gamma_{opt}$ ; $I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	1.9	2.4	dB
		$\Gamma_s = \Gamma_{opt}$ ; $I_C = 10\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $f = 2\text{ GHz}$ ; $T_{amb} = 25\text{ °C}$	–	2.1	–	dB
$P_{L1}$	output power at 1 dB gain compression	$I_C = 40\text{ mA}$ ; $V_{CE} = 8\text{ V}$ ; $R_L = 50\text{ }\Omega$ ; $f = 900\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$	–	21	–	dBm
ITO	third order intercept point	note 2	–	34	–	dBm

## Notes

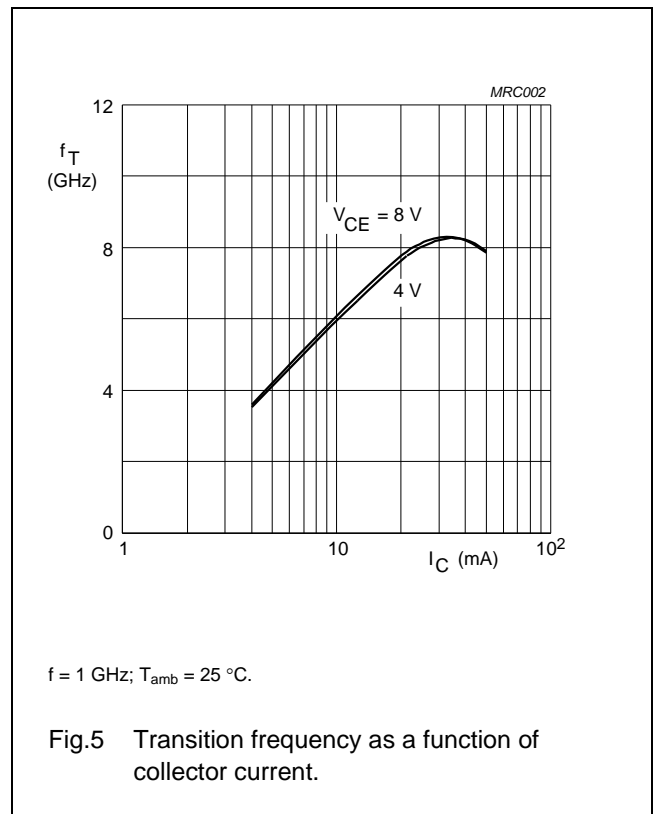
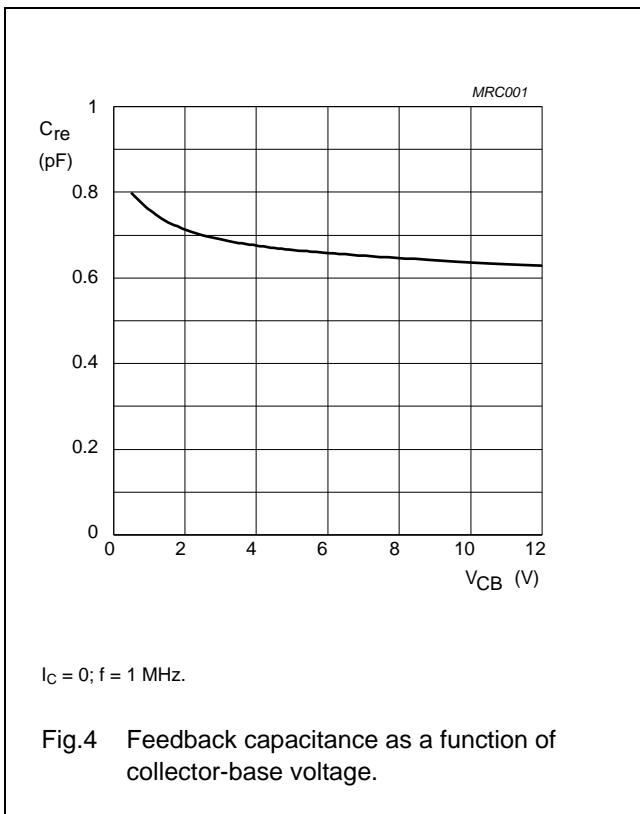
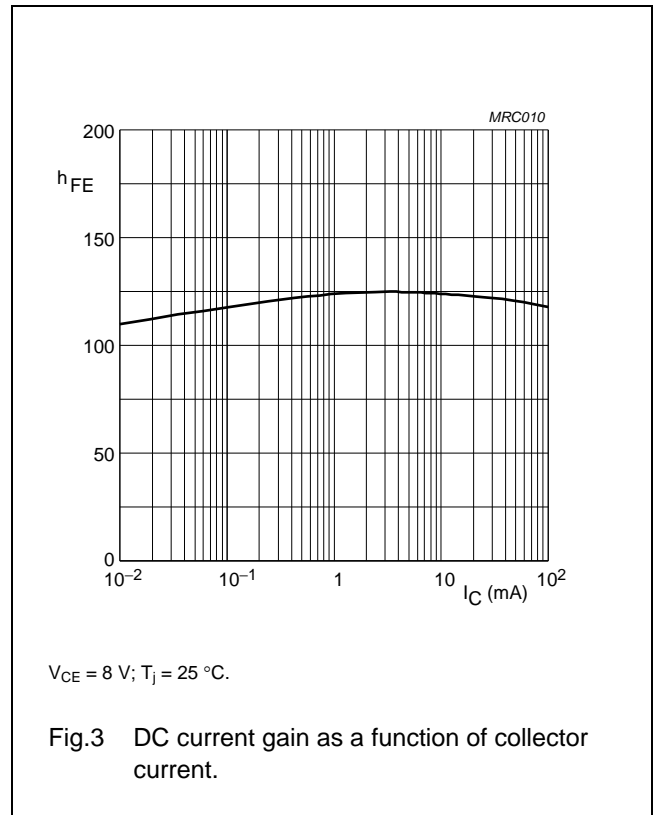
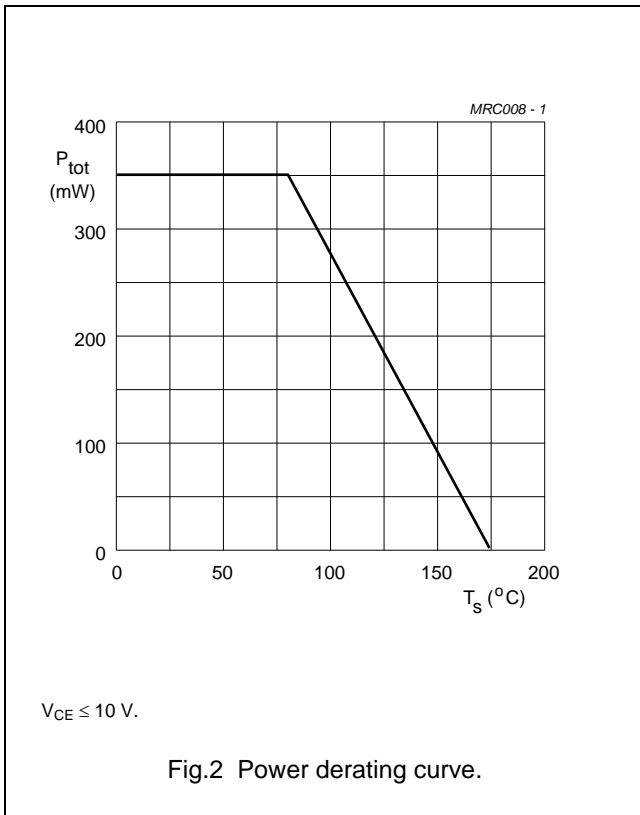
- $G_{UM}$  is the maximum unilateral power gain, assuming  $s_{12}$  is zero and

$$G_{UM} = 10 \log \frac{|s_{21}|^2}{(1 - |s_{11}|^2)(1 - |s_{22}|^2)} \text{ dB.}$$

- $I_C = 40\text{ mA}$ ;  $V_{CE} = 8\text{ V}$ ;  $R_L = 50\text{ }\Omega$ ;  $f = 900\text{ MHz}$ ;  $T_{amb} = 25\text{ °C}$ ;  
 $f_p = 900\text{ MHz}$ ;  $f_q = 902\text{ MHz}$ ; measured at  $f_{(2p-q)} = 898\text{ MHz}$  and at  $f_{(2q-p)} = 904\text{ MHz}$ .

NPN 9 GHz wideband transistor

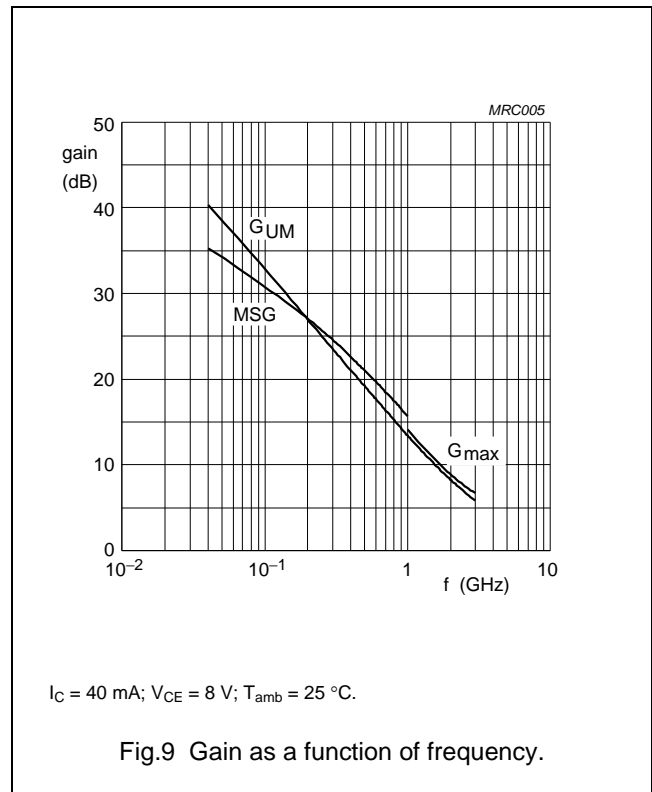
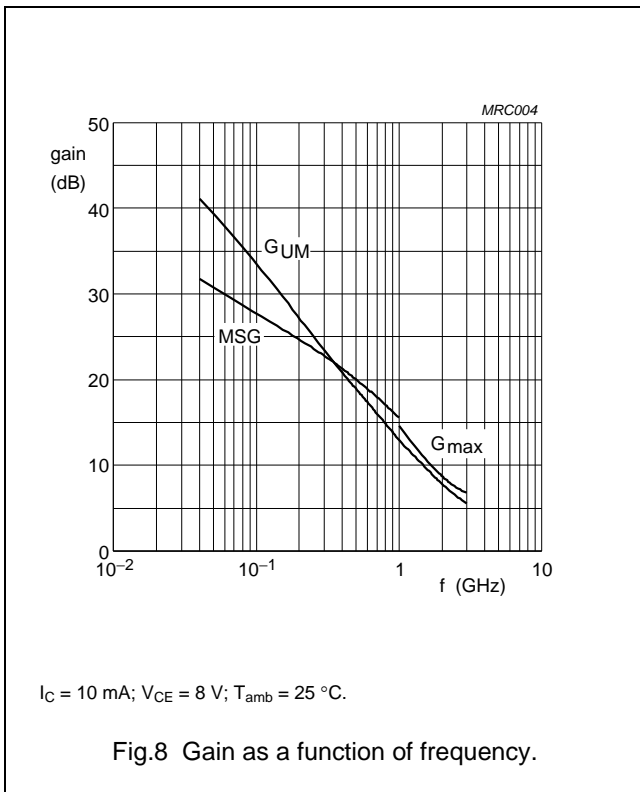
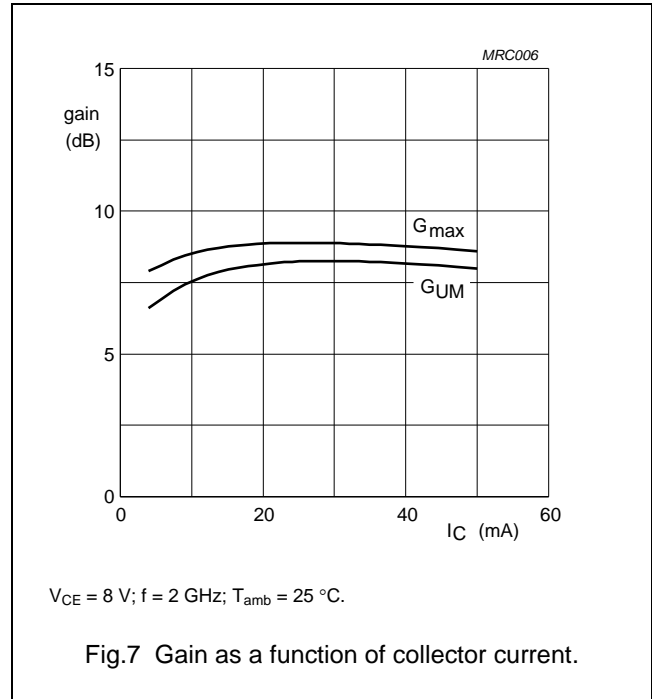
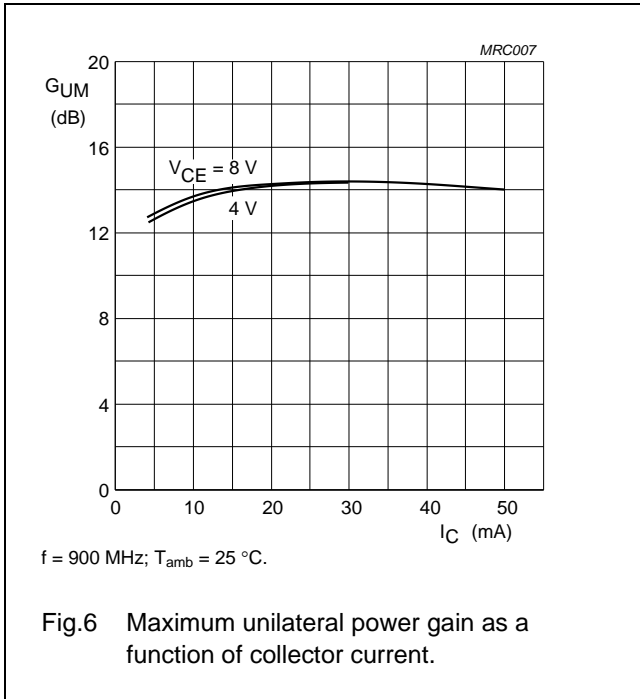
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NPN 9 GHz wideband transistor

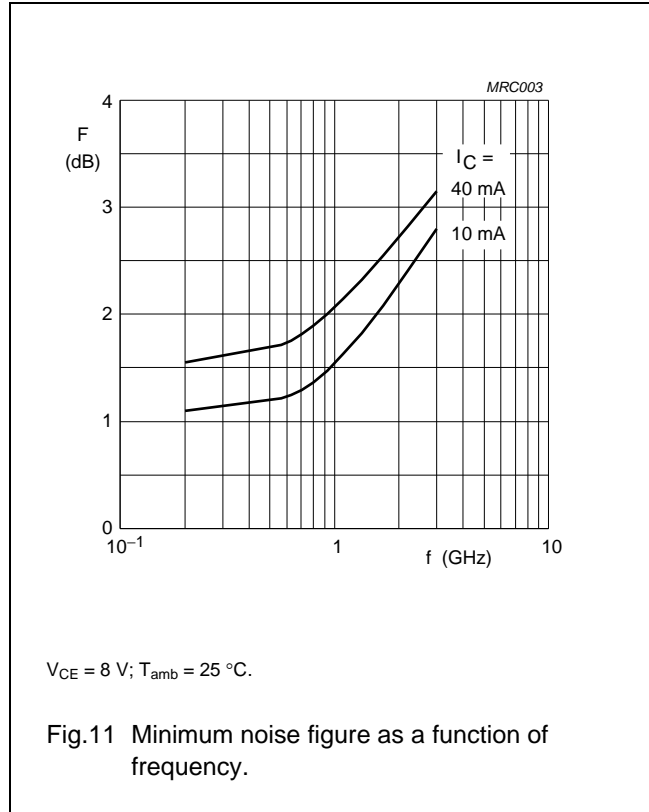
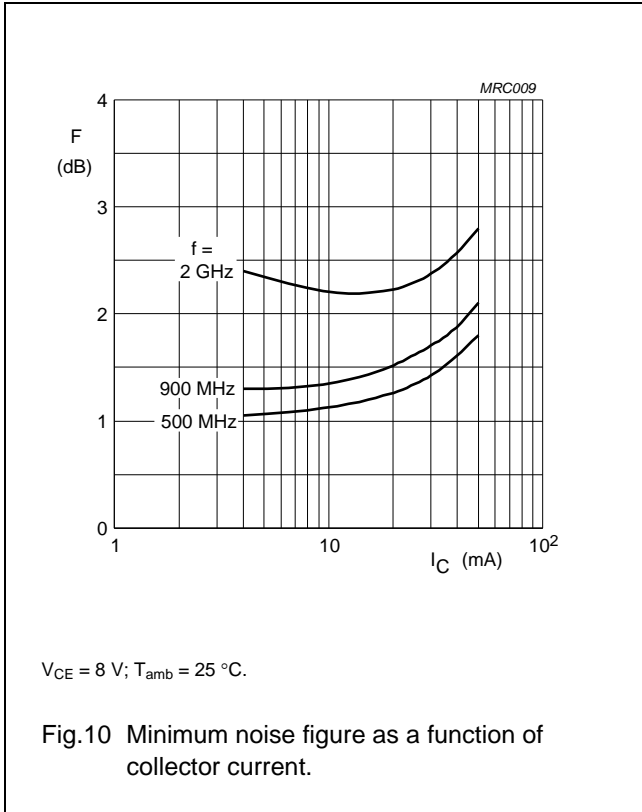
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In Figs 6 to 9,  $G_{UM}$  = maximum unilateral power gain; MSG = maximum stable gain;  $G_{max}$  = maximum available gain.



# NPN 9 GHz wideband transistor

# BFS540



NPN 9 GHz wideband transistor

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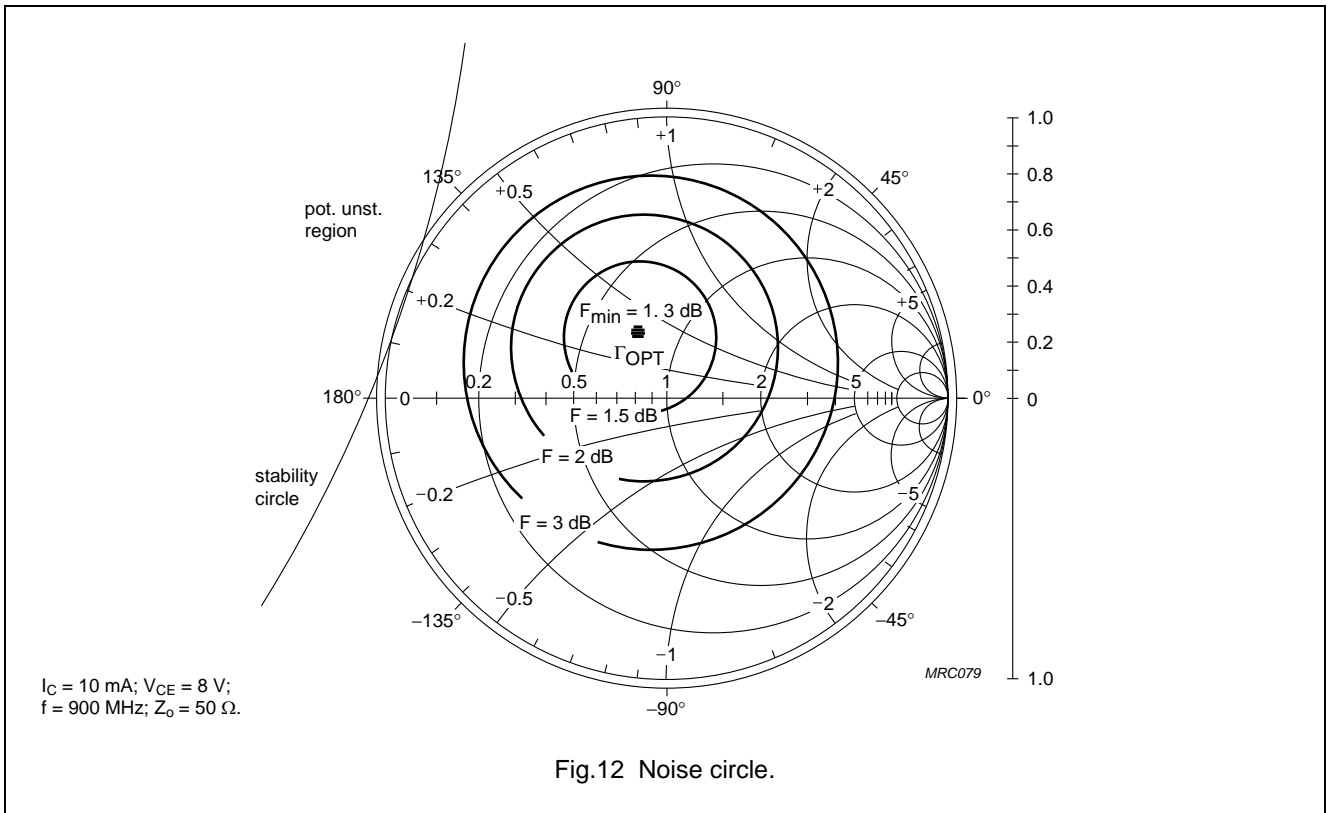


Fig.12 Noise circle.

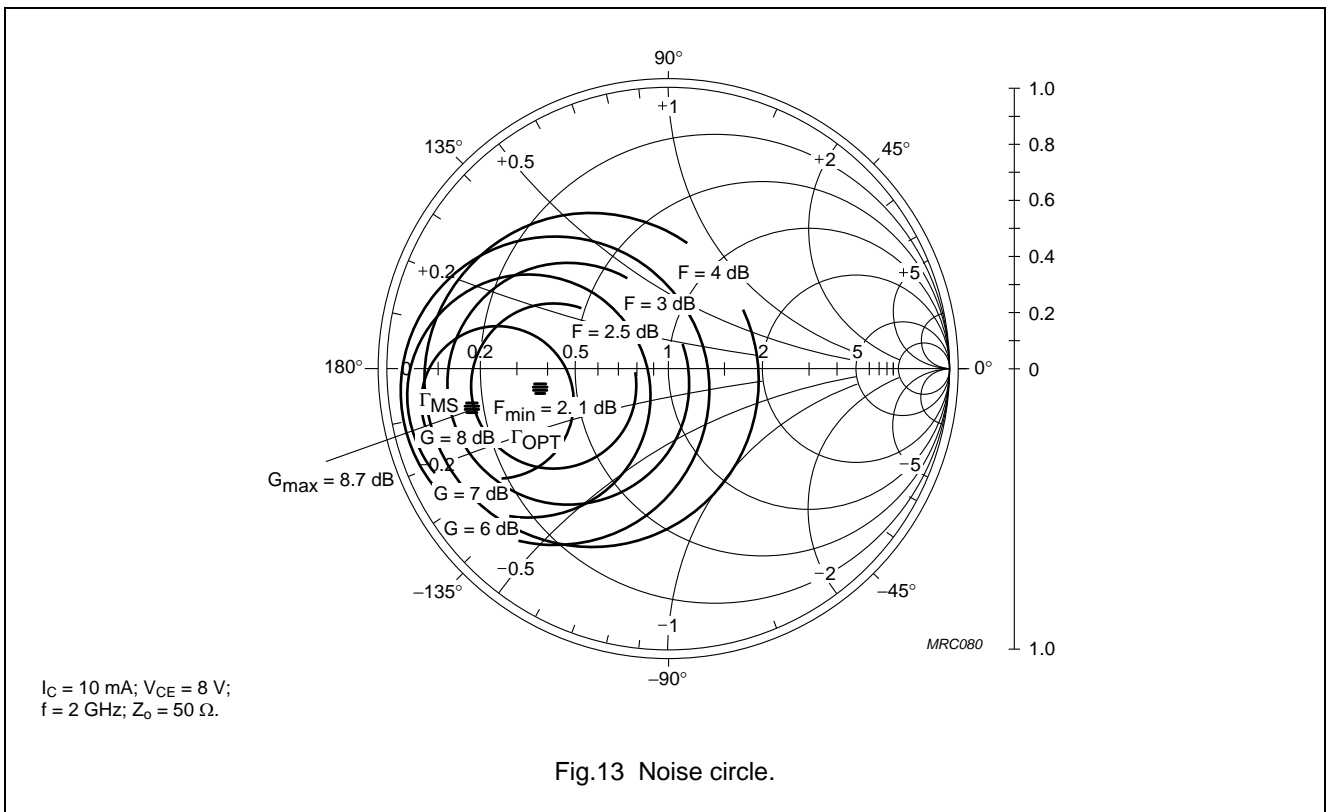
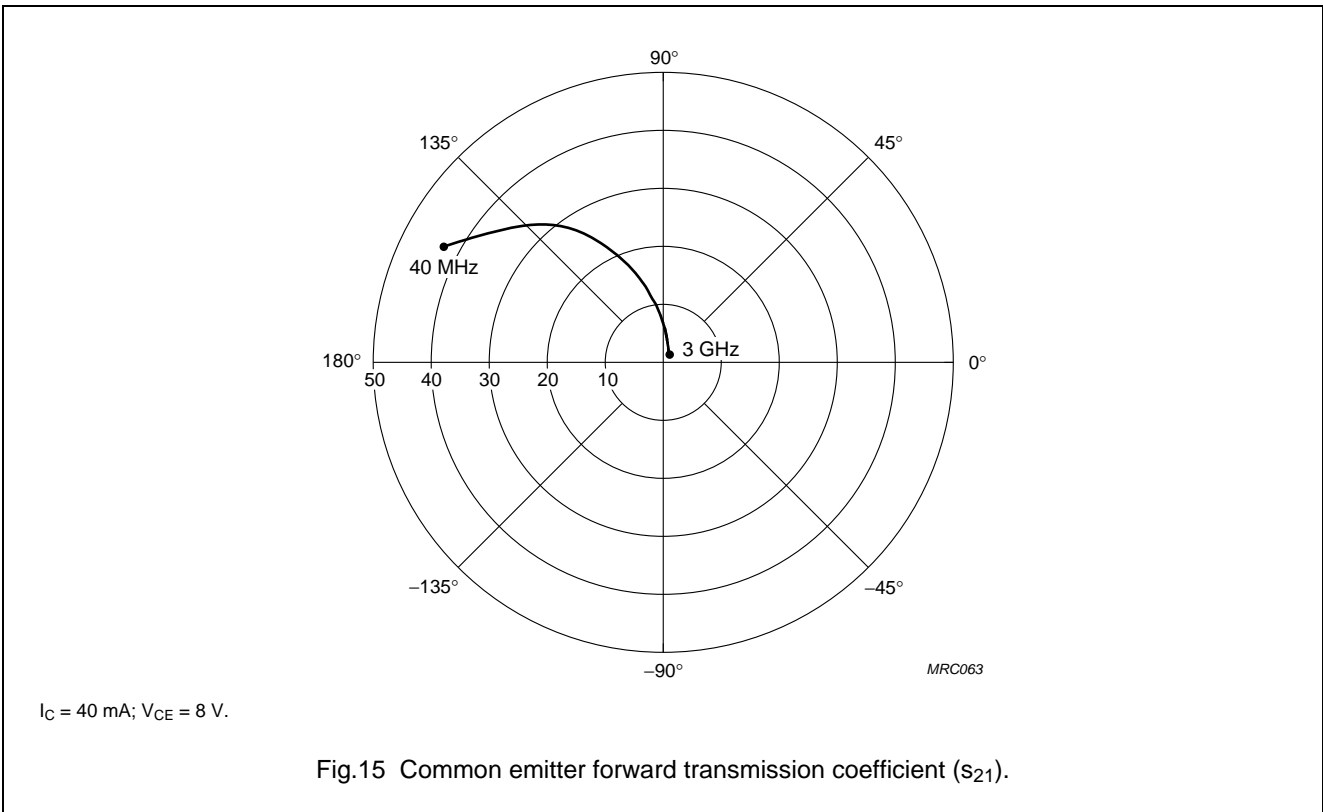
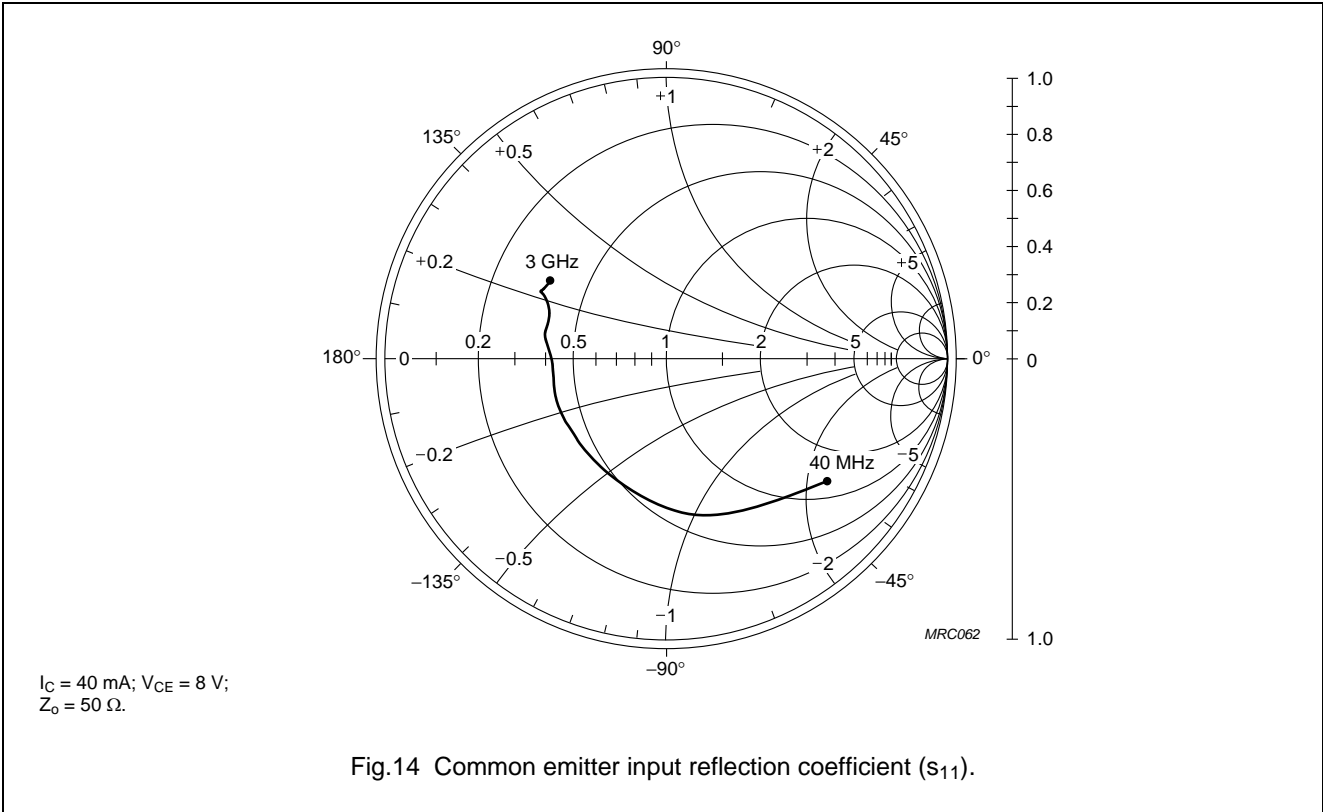


Fig.13 Noise circle.

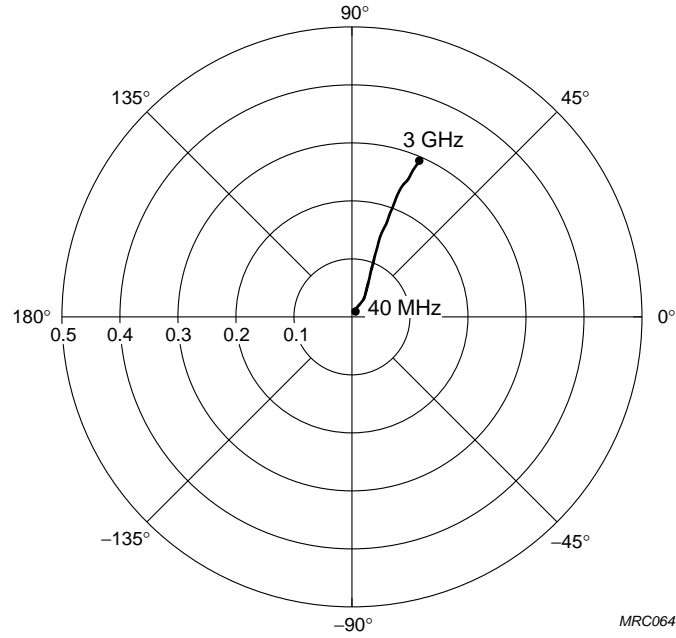
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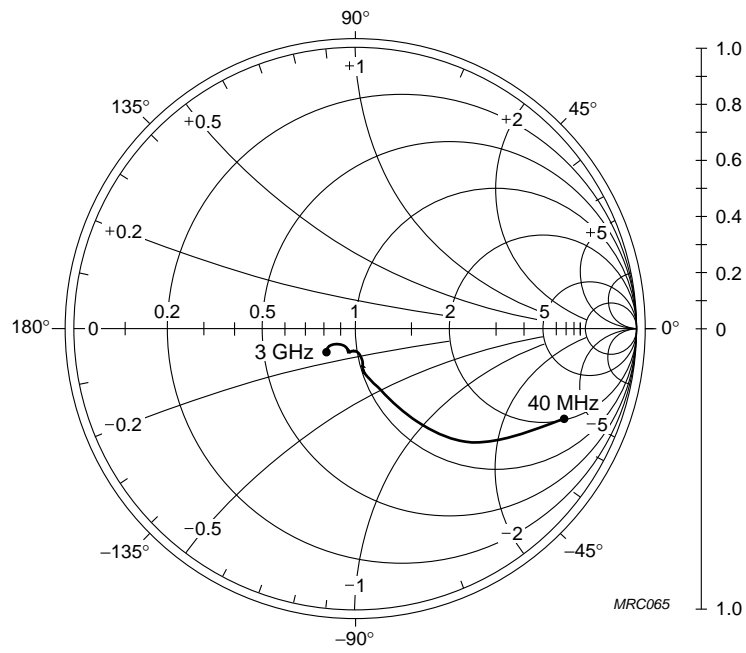
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$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V}.$

Fig.16 Common emitter reverse transmission coefficient ( $s_{12}$ ).



$I_C = 40 \text{ mA}; V_{CE} = 8 \text{ V};$   
 $Z_o = 50 \Omega.$

Fig.17 Common emitter output reflection coefficient ( $s_{22}$ ).

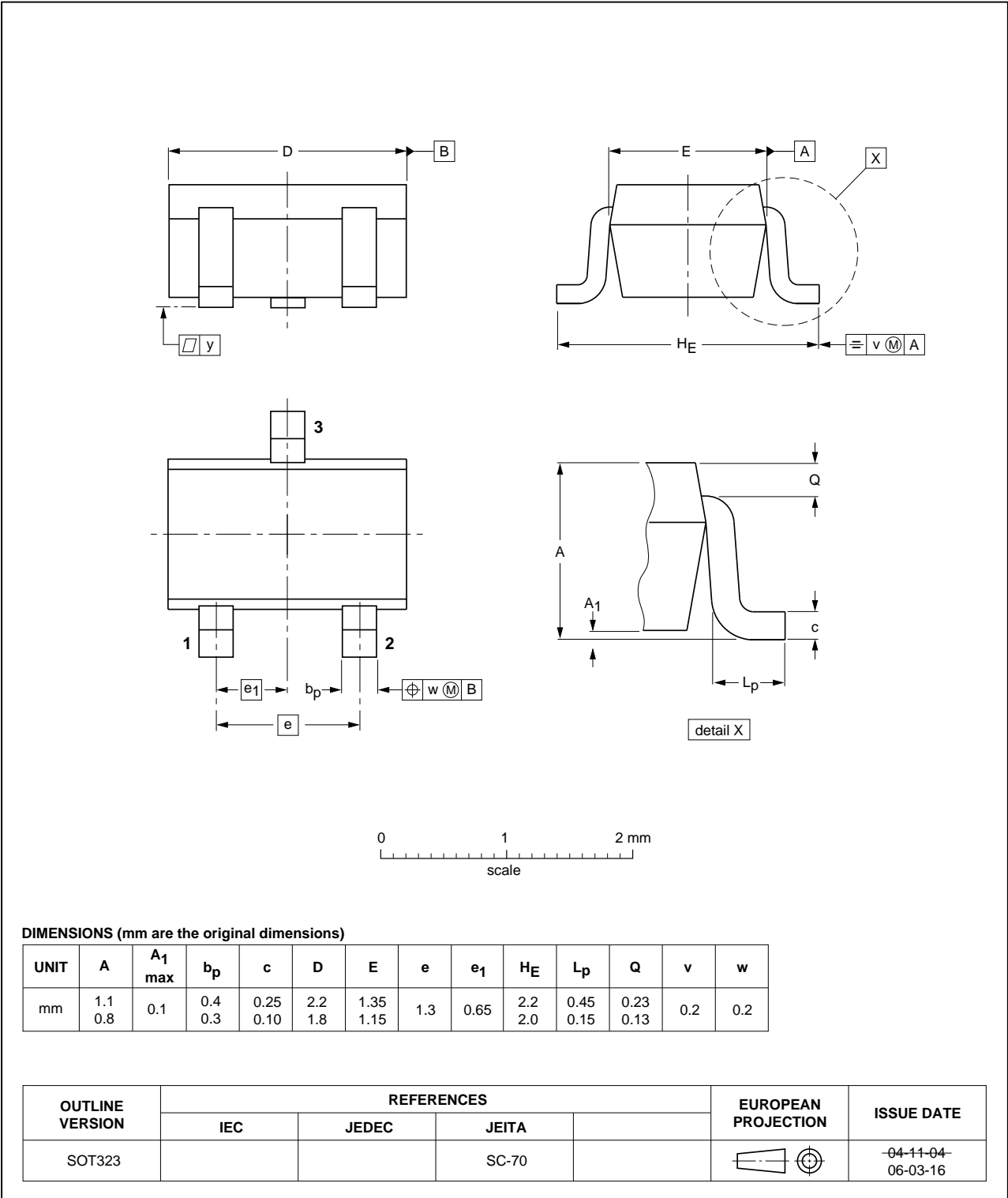
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PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT323



# NPN 9 GHz wideband transistor

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## DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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